# Scanning electron microscopy techniques

# MS-633 Materials Science and Engineering (EDMX)

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http://cime.epfl.ch

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### **Outline**

- Introduction to electron microscopy (EM) (by E. Oveisi)
   Why use electrons?
  - Wavelength and resolution
    Types of interactions
- EM setup (by E. Oveisi)

**Electron sources** 

Lenses

Vacuum system

**Detection system** 

- **SEM** (by E. Oveisi & M. Cantoni)
  - Operation, Signals
  - Contrast mechanism
  - Interpretation of images, Challenges
  - Related techniques
  - Advanced and high-resolution SEM
- Chemical analysis and Monte Carlo simulations (by M. Cantoni)
- Focused ion beam (by M. Cantoni)



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- Introduction to electron microscopy (EM) (by E. Oveisi)
  - Why use electrons?
  - Wavelength and resolution
  - **Types of interactions**
- EM setup (by E. Oveisi)
  - **Electron sources**
  - Lenses
  - Vacuum system
  - **Detection system**
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  - Contrast mechanism
  - Challenges
  - Related techniques
  - Advanced and high-resolution SEM
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What is an electron microscope?

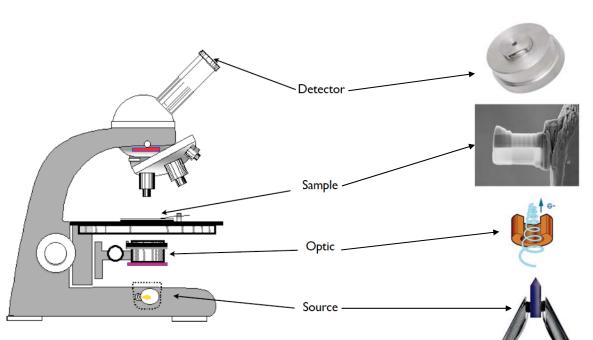






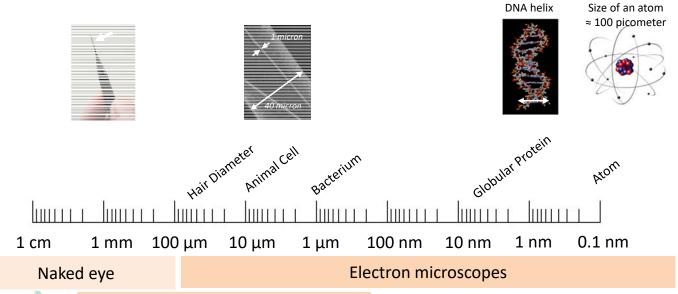


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## Why use electrons as probe?





Conventional light microscopes

Visible light wavelength: 400-700 nm



Electron wavelength: 0.0387 nm @ 1 keV 0.0019 nm @ 300 keV

Developed by Ernst Ruska in 1931 (Nobel Prize in Physics 1986) Electrons have wave-like properties (De Broglie 1924) The electron wavelength depends on its energy Magnetic lenses can be used to focus electrons

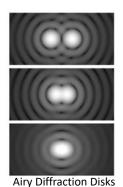
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## Why use electrons as probe?

**Definition of resolution:** The minimum distance that two point-source objects have to be in order to distinguish the two sources from each other. There are two closely related values for the diffraction limit, the Abbe and Rayleigh criterions.



	0.1	Aberration-
	1	corrected EM
smo	10	Electron
Angstroms	100	Microscope
	1000	TEM ASTEM
	10 <sup>4</sup>	Light Microscope
	10 <sup>5</sup>	0 1840 1880 1920 1960 2000 2044

Abbe's definition of maximum resolution of an optical system states that the smallest feature resolved is limited by diffraction.

• Abbe diffraction limit for the light microscope

(around 1000 atomic diameter) around half of the wavelength

Equivalent for the electron microscope

25-50 x wavelength

\* NOTE: Lens aberrations limit spatial resolution Spherical and Chromatic Aberration corrections allow for 0.05 nm resolution at 300 kV

# Why use electrons as probe?

			Advantageous	Disadvantageous
		Visible light	Not very damaging Easily focused Eye detector	Long wavelengths (400 nm)
		X-rays	Small wavelength (Angstrom) Good penetration	Hard to focus Damage sample
•	High en Easy to Easily m		Low sample damage Small wavelength (pm)	How to produce? How to focus?
•	Interact	Electrons	Small wavelength (pm) Can be focused	Damage sample Poor penetration

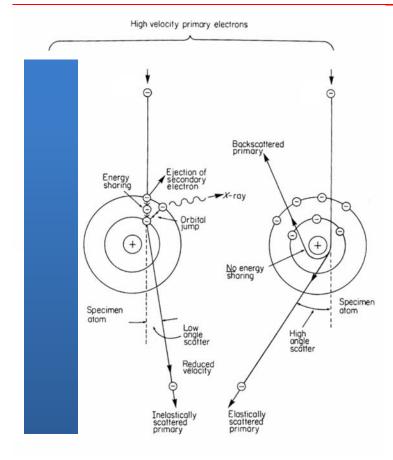
Electron microscopes are used not only for obtaining good resolution images but also:

- can be used as a diffractometer
- for chemical analyses
- · for imaging/measuring strain field in the sample
- etc.

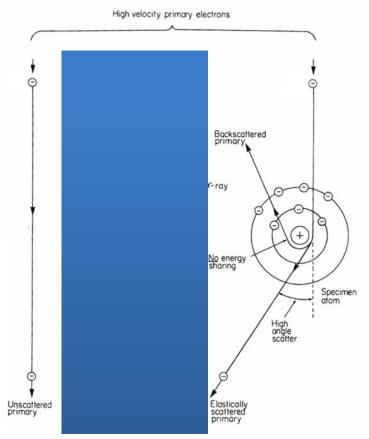
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# Three classes of scattering outcomes



## Three classes of scattering outcomes



**Inelastic events** occur when the electron beam interacts with the electric field of a specimen atom electron.

The result is a **transfer of energy** to the specimen atom and a potential expulsion of an electron from that atom as a **secondary electron (SE)**. SEs by definition are less than 50 eV.

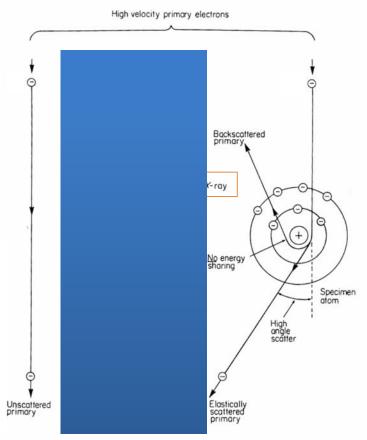
If the vacancy due to the creation of a secondary electron is filled from a higher level orbital, an X-Ray characteristic of that energy transition is produced.

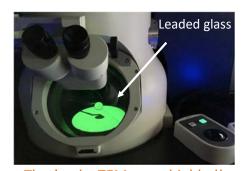
Energy transfer (loss) - reduced velocity -> Will be focused more strongly by the lenses, at a plane higher up in the microscope than the electron that are scattered/elastically scattered

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## Three classes of scattering outcomes

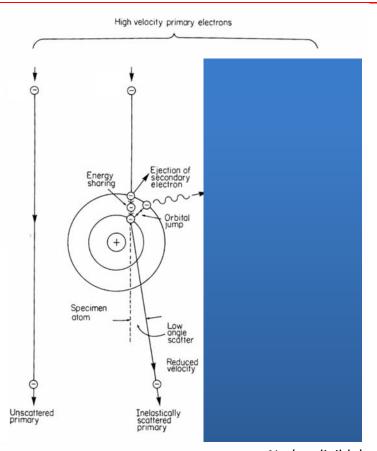




That's why TEMs are shielded!

Reduced velocity -> Will be focused more strongly by the lenses, at a plane higher up in the microscope than the electron that are scattered/elastically scattered

## Three classes of scattering outcomes



**Elastic events** occur when a beam electron interacts with the electric field of the nucleus of a specimen atom, resulting in a change in the direction of the beam electron without a significant change in the energy of the beam electron (< 1 eV).

If the elastically scattered beam electron is deflected back out of the sample, the electron is termed a **backscattered electron (BSE)**.

Back Scattered Electron

Elasticly Scattered Electron

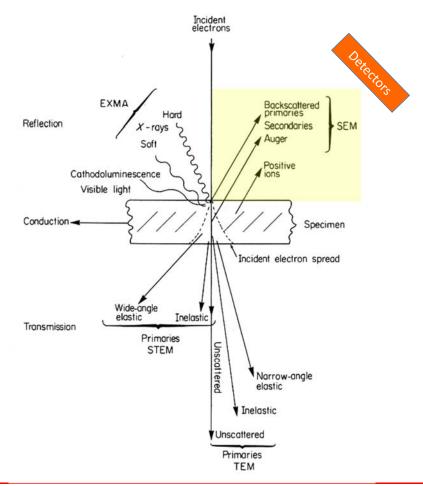
No (negligible) energy transfer
High angle scattering for elastically scattered electrons

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## Types of electron microscopes

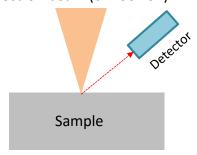


### Reflected signal from:

- back-scattered electrons
- secondary electrons (emitted by the sample)
- · Positive ions
- etc.

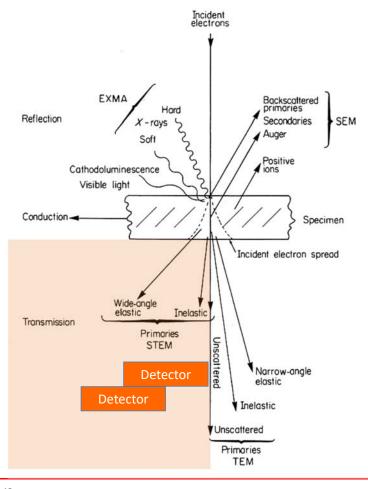
### **Scanning Electron Microscopy**

Electron beam (0.2-30 keV)



Convergent illumination (= probe) Scanning (moving beam) mode

# Types of electron microscopes

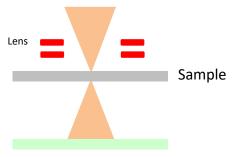


### Transmitted signals from:

- Elastically scattered electrons
- inelastically scattered electrons
- · Diffuse scattering events
- etc

### **Scanning Transmission Electron Microscopy**

Electron beam (60-300 keV)



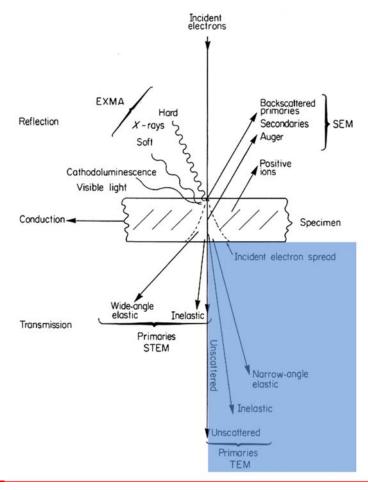
Convergent illumination Scanning mode

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# Types of electron microscopes

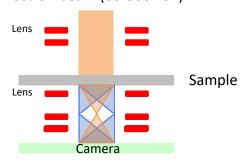


Images is created through the interference between the:

- Unscattered primary electrons (transmitted beam)
- Narrow-angle elastically scattered (diffracted) electrons

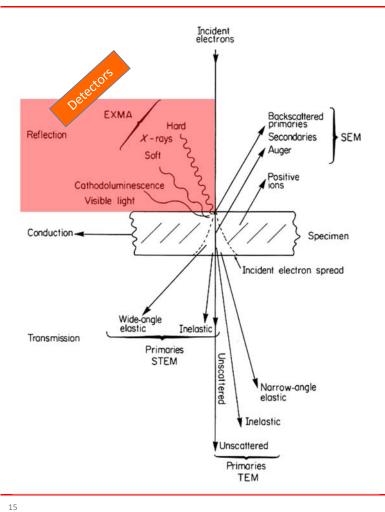
### **Transmission Electron Microscopy**

Electron beam (60-300 keV)



Parallel illumination

# Types of electron microscopes



Inelastic events will ionize atoms, when they relax they emit:

- X-ray signals (characteristic X-rays)
- Photons (IR, UV)
- Visible light (Cathodoluminescence)
- Etc.

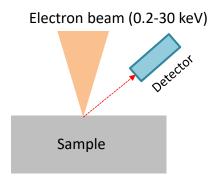
EXMA: Electron Probe X-ray Microanalyser

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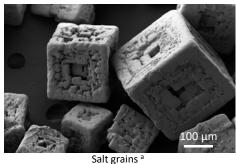


## Types of electron microscopes

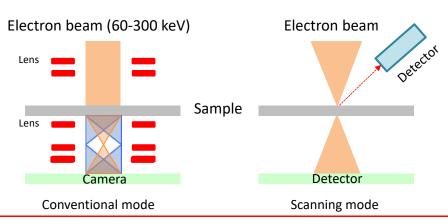
## Scanning electron microscope (SEM):

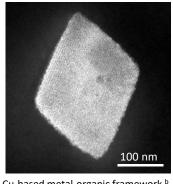


Signals: Secondary electrons, Back-scattered electrons, X-ray, Auger, ...



## Transmission electron microscope (TEM):

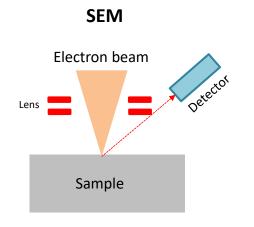


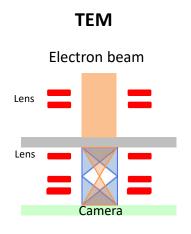


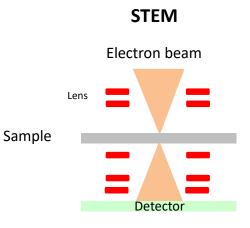
Cu-based metal-organic framework b

- a http://www.trente.eu
- <sup>b</sup> D. Sun et al., ACS Central Science 2018.

## Components of an electron microscope





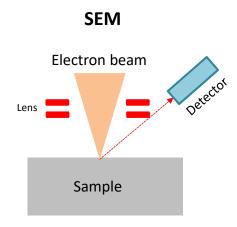


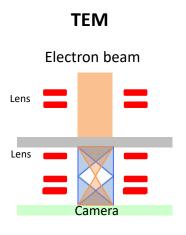
Vacuum system
Electron gun
Lenses
Detectors

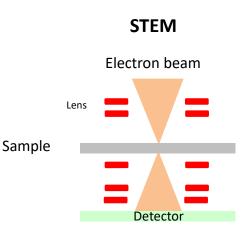
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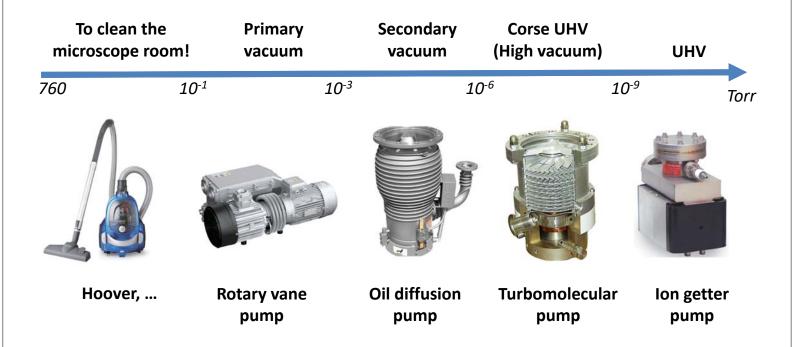
## Components of an electron microscope - Vacuum system







- 1. Electron propagation is only possible through vacuum!
- 2. Need a good vacuum system to reduce contamination!

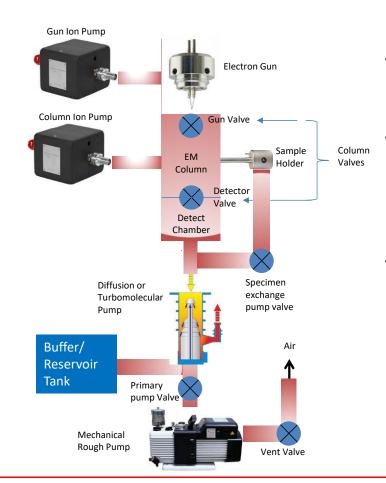


Different kinds of vacuum pumps have different range where they are effective



## Vacuum system

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- Primary vacuum (>0.1 Pa)
  - Mechanical pump
- Secondary to high vacuum
   Detector or viewing chamber (<10<sup>-4</sup> Pa)

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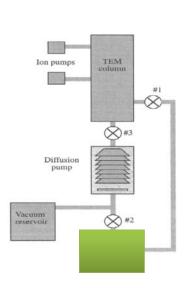
- Oil diffusion pump
- Turbomolecular pump
- High and ultra-high vacuum
   Gun & specimen area (<10<sup>-6</sup> Pa)
  - Ion getter pump
  - Cold trap

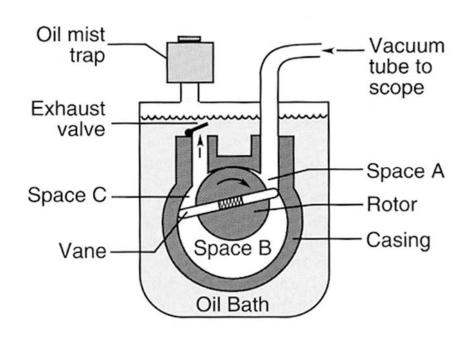


## Vacuum system – Primary vacuum

### Rotary vane pump

- Uses oil
- noisy





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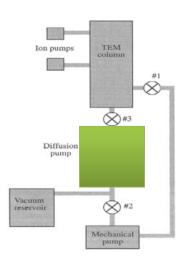


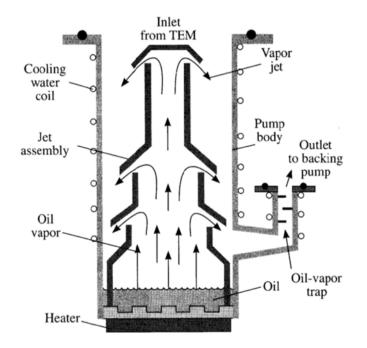
## Vacuum system – Secondary vacuum

## Oil diffusion pump

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- Vibration free
- Contamination possible oil vapor
- High pumping capacity (>500 l/s)
- Best with cold trap

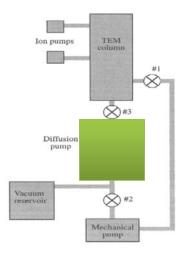


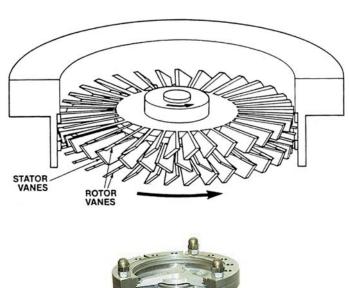


## Vacuum system – Coarse UHV

## **Turbomolecular pump**

- Rotation speed 20-50'000 rpm
- Magnetic bearings
- Pumping volumes 50-500 l/s







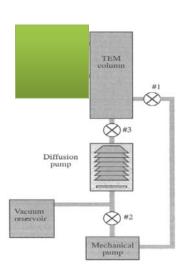
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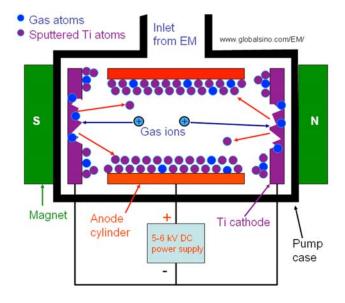


## Vacuum system – Ultra-high vacuum

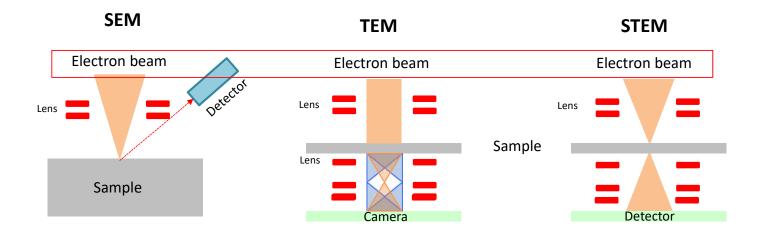
## Ion getter pump

- no vibrations
- No exit: improves vacuum!



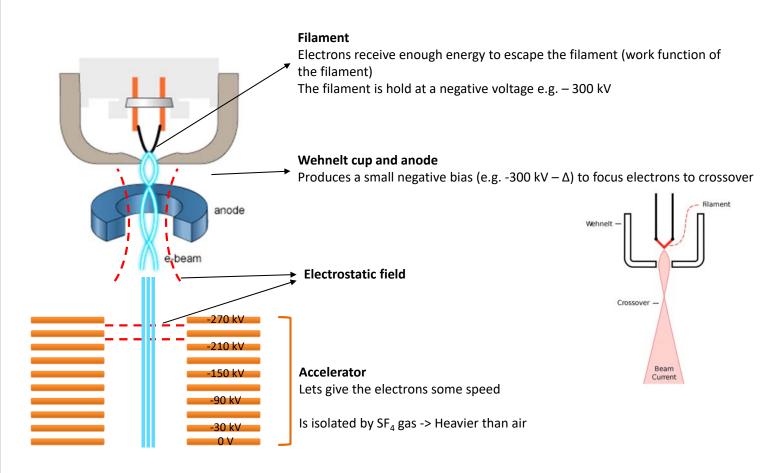


## Components of an electron microscope – Electron gun





## **Electron gun**



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## **Electron gun**

Intensity











### **Spatial coherency:**

Do all the electrons com form the same direction?

An electron beam emanating from a small source size is said to have high spatial coherency.

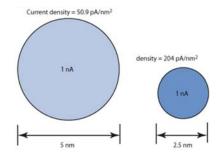
### **Temporal coherency**:

Do all the electrons have exactly the same speed/energy?

A beam with high **temporal coherency** will have electrons of the same wavelength.

### **Important parameters**

- Source and crossover size: determines the probe size (→ resolution)
- Energy spread: temporal coherency
- · Emitted current and current density
- Brightness: current per surface unit and per solid angle
- Current stability
- · Vacuum needed



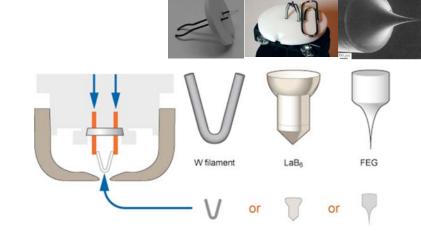
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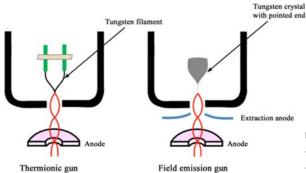


## **Electron gun**

### Two types of emission guns:

- Thermionic gun
  - W or LaB<sub>6</sub> crystal
- Field emission gun (FEG)
   Cold FEG
   Schottky FEG





#### In a FEG:

- High field E≈10<sup>9</sup>V/m
- First anode = extractor (always constant)
- Second anode = accelerator

# Electron gun - Thermionic gun

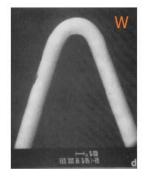
- Filament is heated to overcome the work-function to release electrons to vacuum level.
- Tungsten wire heated to ~2800K
- LaB<sub>6</sub> crystal heated to 1900K



Simple to use Cheap No ultra-high vacuum required Maintenance friendly

#### **Disadvantages**

Low brightness High energy spread Large source size (10-100 □m)





### Thermionic gun

Analogous to volcano

More electrons form a large tip (10-100 @m)

Different energies

Different energies
Different directions

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## Electron gun - Field emission gun

- The strength of an electric field E is considerably increased at sharp points.
- Lowers the work-function barrier so that electrons can tunnel out of the filament (usually tungsten).
- Surface has to be pristine (no contamination or oxide)

Ultra-high vacuum condition (Cold FEG) or poorer vacuum if tip is heated ("thermal" FEG; ZrO surface

treatments → Schottky emitters).

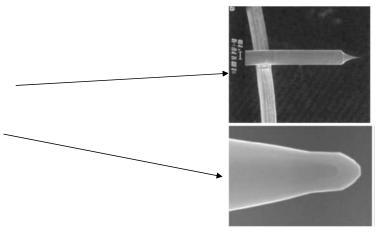
- Cold field emission (E≈10<sup>9</sup> V/m)
  W mono-crystal with sharp tip
  tip radius ~100nm
- Thermally assisted emission: Shottky effect W/ZrO tip at 1700-1800K



Small energy dispersion (< 0.4 eV)
High coherence
High brightness
→ higher resolution at lower energies

#### **Disadvantages**

Expensive
Ultra-high vacuum necessary
Cold FEG needs flushing (cleaning) after ~8 hrs



#### **FEG**

Analogous to child's slide

Electrons from a very sharp tip radius ~100nm Same energy Same direction

# Characteristics of principal electron sources at 200 kV

	W	LaB6	FEG Schottky (ZrO/W)	FEG cold (W)
Crossover size (nm)	>10 <sup>5</sup>	10 <sup>4</sup>	10-100	3
Emission current (µA)	100	20	100	20~100
Current density (A/m²)	5	10 <sup>2</sup>	10 <sup>5</sup>	10 <sup>6</sup>
Brightness B (A/m <sup>2</sup> sr)	5x10 <sup>9</sup>	5x <sub>0</sub> 10 <sup>1</sup>	5x10 <sup>12</sup>	10 <sup>13</sup>
Energy spread ΔE (eV)	2.3	1.5	0.6~0.8	0.3~0.7
Current stability (%/hr) * Might be one order lower	<1	<1	<1	5
Vacuum pressure (Pa)*	10 <sup>-3</sup>	10-5	10 <sup>-7</sup>	10 <sup>-8</sup>
Vacuum temperature (K)	2800	1800	1800	300

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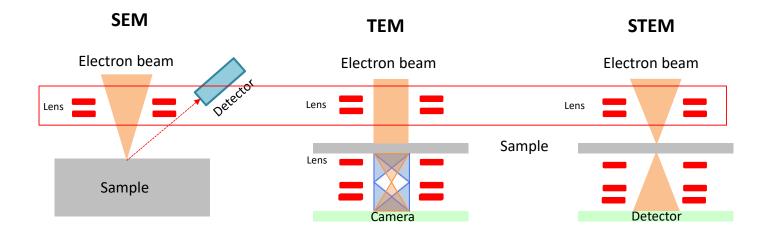


# **Electron gun**

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W Advantages:	LaB <sub>6</sub> advantages:	FEG advantages:			
Rugged and easy to handle	High brightness	Extremely high brightness			
Requires only moderat vacuum	High total beam current	Long life time, more than 1000 h.			
Good long time stability	Long life time (500-1000h)				
High total beam current					
W disadvantages:	LaB <sub>6</sub> disadvantages:	FEG disadvantages:			
Low brightness	Fragile and delicate to handle	Very fragile			
Limited life time (100 h)	Requires better vacuum	Current instabilities			
	Long time instabilities	Ultra high vacuum to remain stable			

## Components of an electron microscope – Lenses

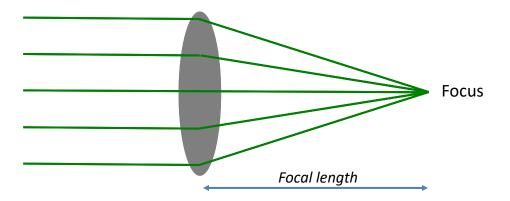


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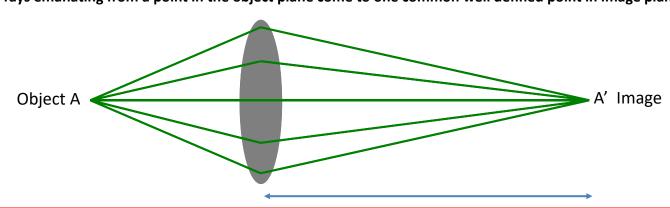


# **Properties of the lenses**

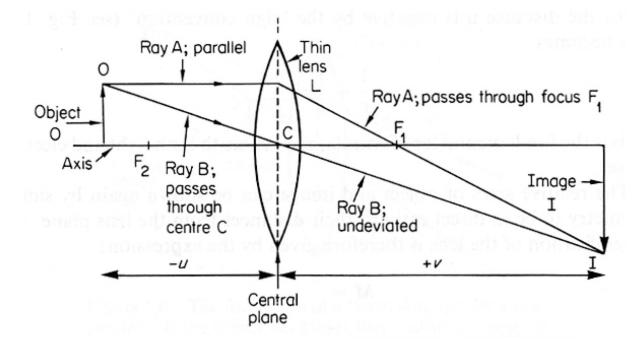
### Lens bends beams to focus it to a point.



The rays emanating from a point in the object plane come to one common well defined point in image plane.



### Lens produces a magnified (or de-magnified) image

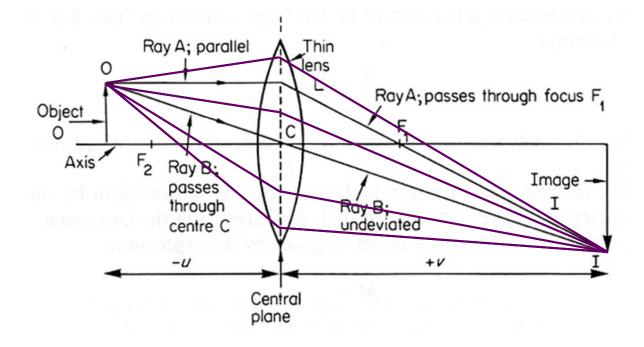


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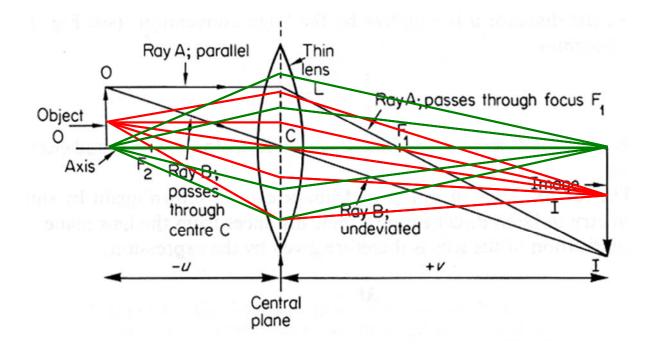


## **Electron optics - Lenses**

## Lens produces a magnified (or de-magnified) image



### Lens produces a magnified (or de-magnified) image



Thin lens equation: 1/f = 1/u + 1/vMagnification = v/u



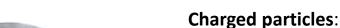
## **Electron optics - Lenses**



### Light:

Glass or polymer lenses

Deflection of light through changing refraction index





Lorentz Force! Electrostatic lenses Magnetic lenses

## Particularity:

Variable focus

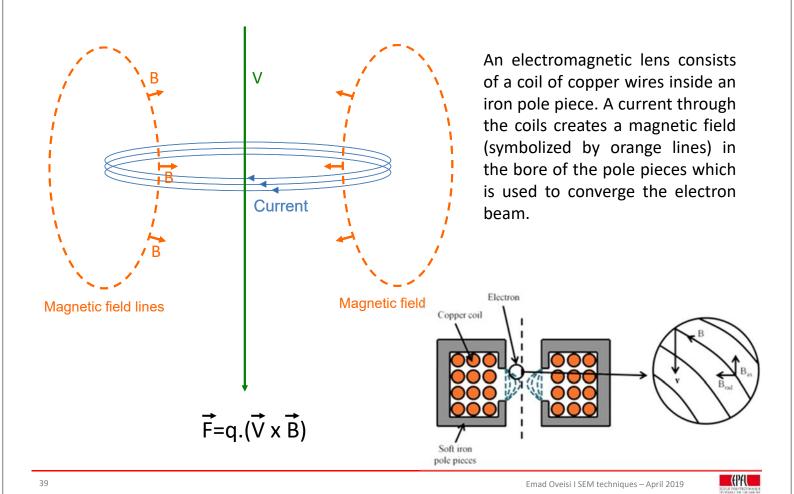
Tuneable correctors (astigmatism)

**NOTE:** Electron microscopes have more than one electromagnetic lens. Under this circumstance the image plane of the  $n_{th}$  lens becomes the object plane of the  $(n+1)_{th}$  lens.

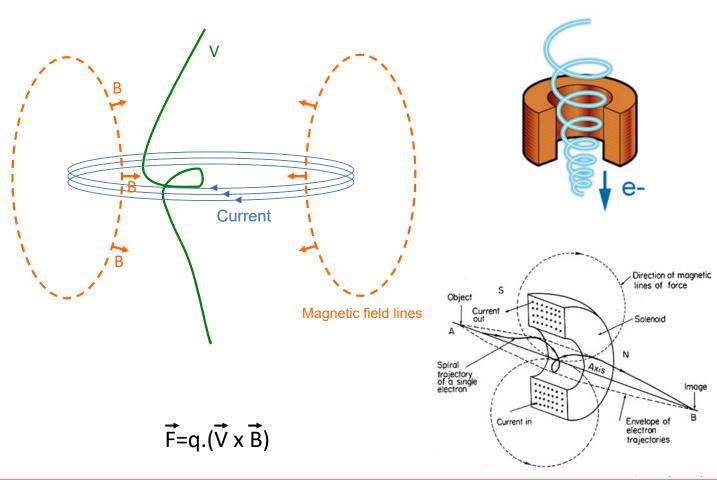
The total magnification is the product of the magnification of all the lenses.

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## **Electron optics - Lenses**

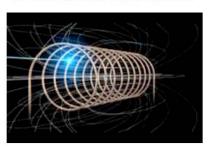


# Electron optics - Lenses



# Electron optics - Lenses

An electron enter inside a solenoïd

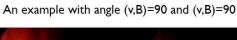


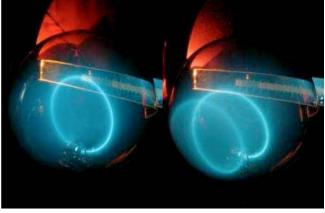
The Lorentz force is then applied



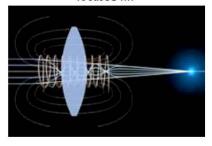
Due to the force, the trajectory is helical







Due to the field shape, the electrons are focused !!!!



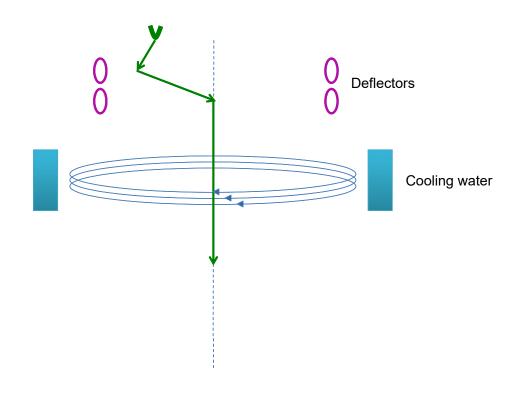
Slide from F. Houdellier, CNRS-France

onde from transaction, erritor trans

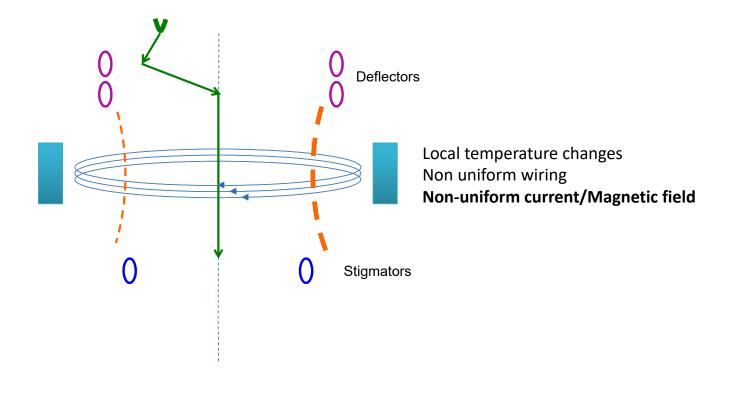
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# Electron optics - Lenses



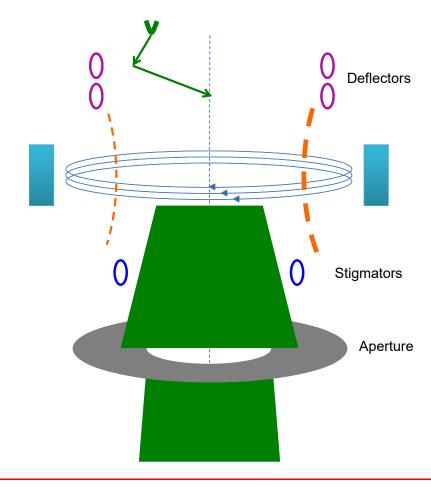
# Electron optics - Lenses



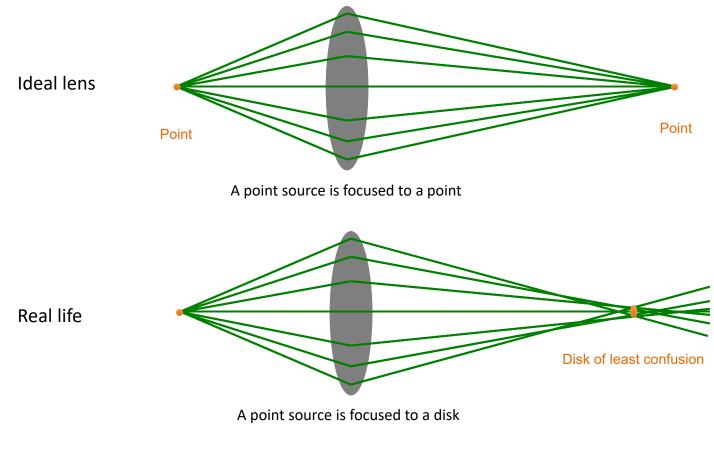
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# Electron optics - Lenses



## **Electron optics - Aberrations**



Lens aberrations reduce resolution!

**Electron optics - Aberrations** 

## 7.50....

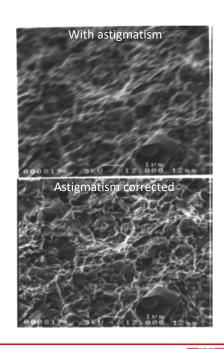
## Lens aberrations

- Chromatic aberration
- Spherical aberration
- Astigmatism
- Diffraction effect



Lens aberrations are one of the main limitations to obtaining high spatial resolution.

**BUT** astigmatism can be easily corrected.

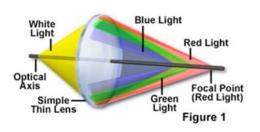


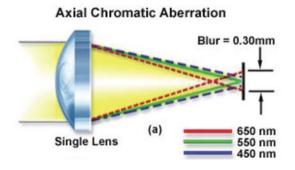
(PAL

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## **Electron optics: Chromatic aberrations**

- Chromatic aberration is distortion that occurs when there is a failure of a lens to focus all colors (wavelengths) to the same convergence point.
- Electrons of lower energy will be bent more strongly.
- Correcting the aberration is necessary, otherwise the resulting image would be blurry and delocalized, a form of aberration where periodic structures appear to extend beyond their physical boundaries.
- Increases with source energy spread.
- Decreases with increasing electron energy  $(E_0)$





Critical for non-monochromatic beams (e.g. Thermionic and Shottky sources)

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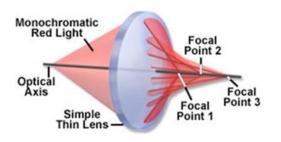


## **Electron optics: Spherical aberration**

- Spherical aberration occurs when parallel illumination rays that pass through the central region of the lens focus farther away than the illumination rays that pass through the edges of the lens.
- Result is multiple focal points and thus a blurred image.
- The diffraction and the spherical aberration limits on resolution have an opposite dependence on the angular aperture of the objective





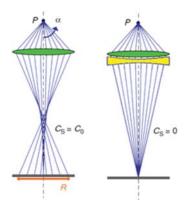


Longitudinal and Transverse Spherical Aberration Paraxial Peripheral Circle **Focus** (3) Transverse Spherical Aberration Longitudinal Spherical Simple Aberration

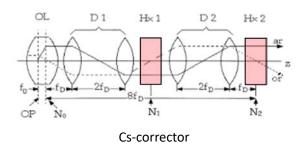
Focal length depends on the distance from optical axis Image of the object is dispersed along the optical axis Circle of least confusion  $d_s = \frac{1}{2} C_s \lambda^{3ar}$ 

### **Electron optics: Spherical aberration correctors**

Light optics: Correction with combination of convex and concave lenses



Electron optics: Correction with hexapole or quadrupole and octopole lenses



http://www.sfc.fr/Material/hrst.mit.edu/hrs/materials/public/ElecMicr.htm

Fig 1 Column of 2000 State Statemary with Convention installed

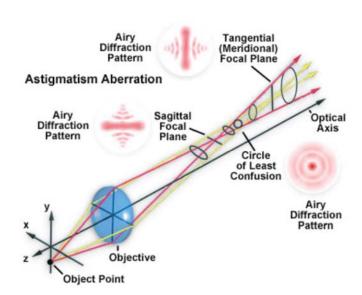
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## COLUMN TRANSPORTE

## **Electron optics: Astigmatism**

Focal length varies for different axes of the lens.

Image will appear "stretched" with changing the focus



## Caused by:

- imperfections in the manufacturing of the pole-piece and the copper windings
- Stray magnetic field

Under focus image

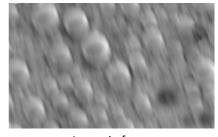
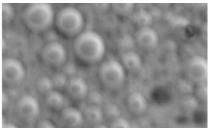


Image in focus

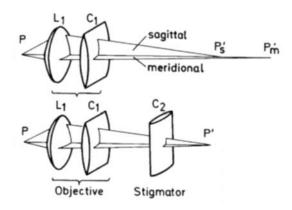


Over focus image



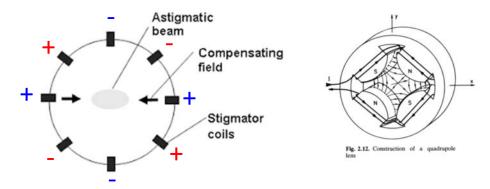
## **Electron optics: Astigmators**

Light optics: correction with cylindrical lenses



Electron optics: Correction with quadrupole lenses

2 quadrupole lenses under 45 degree allow to control strength and direction of correction

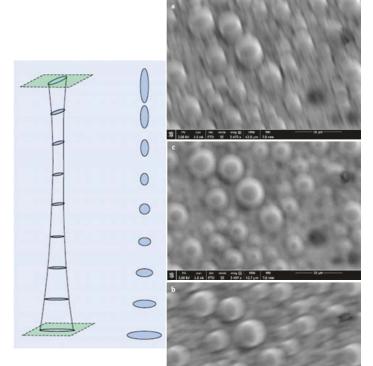


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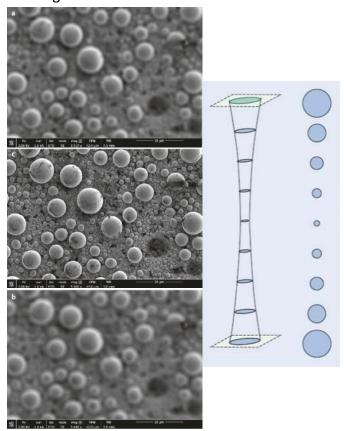


# **Electron optics: Astigmatism**

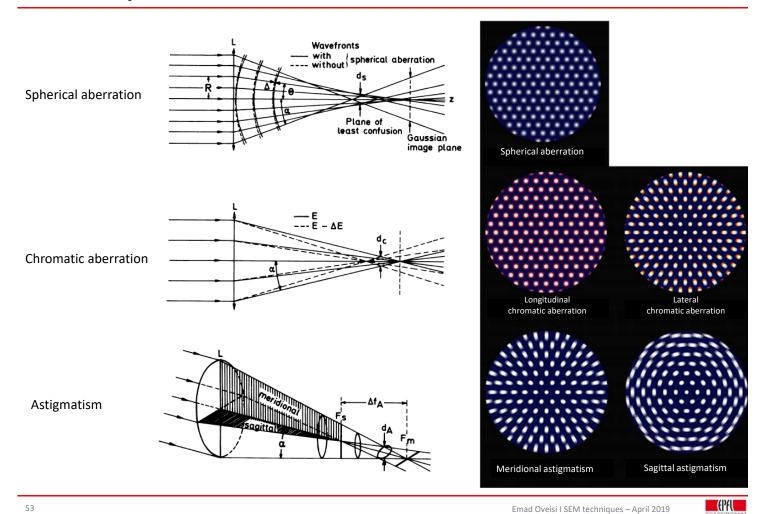
With astigmatism



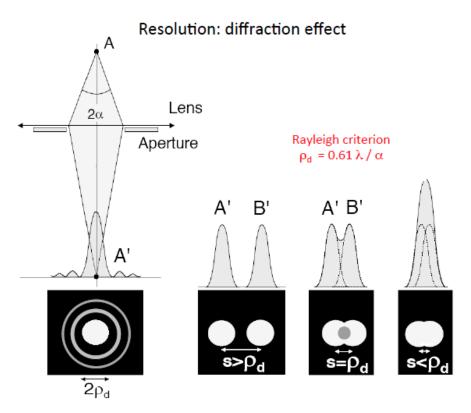
### Astigmatism corrected



## **Electron optics: Aberrations**

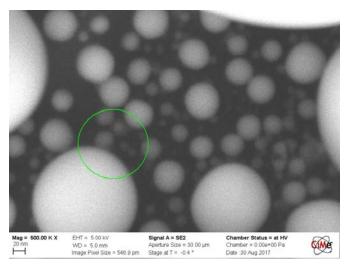


# **Electron optics - Aberrations**

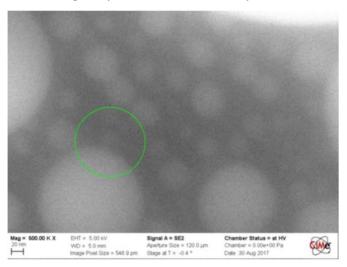


The diffraction and the spherical aberration limits on resolution have an opposite dependence on the angular aperture of the objective lens.

## Optimal Aperture size (30µm)



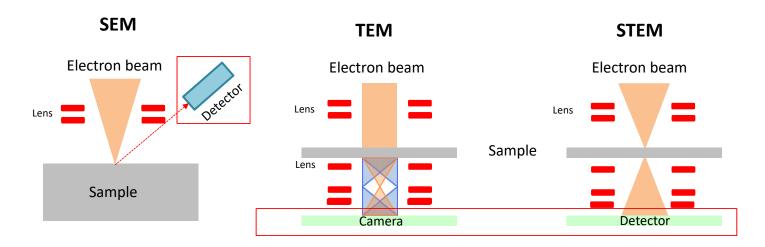
### Large Aperture size (120µm)



Though large apertures produce larger convergence angles (less diffraction effect), spherical aberration increases probe size and reduces resolution



## Components of an electron microscope - Electron detection system



### Photomultiplier

- Everhart-Thornley detector

### Semiconductor BSE detector

- Silicon diode with a p-n junction

#### BSE Robinson detector

- Large scintillator/fiber optic

In-lens detectors

Phosphor screen

Films and image plates

#### Cameras:

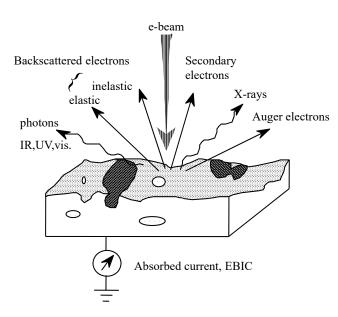
- semiconductor charge-coupled devices (CCD)
- complementary metal-oxide-semiconductor (CMOS)
- Direct electron

Energy filters and spectrometers + CCD

Disk/ring shape detectors

Pixelated detectors

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### **Electron signals:**

### Secondary electrons SE

Electrons ejected from material at low energies Topography, low energy  $\approx 5-50 \text{ eV}$ 

### **Backscattered electrons BSE**

Incident electrons that elastically scatter and leave the sample Atomic number Z

Energy  $\approx$  eV<sub>0</sub> (range from 50 eV to an energy close to initial energy)

### **Auger electrons**

Ejected electrons with an energy characteristic of target elements

Not detected in conventional SEM, surface analysis

### Other signals:

Electromagnetic radiations etc.

Phonos: visible, UV, IR

Absorbed current, electron-holes pairs creation, EBIC

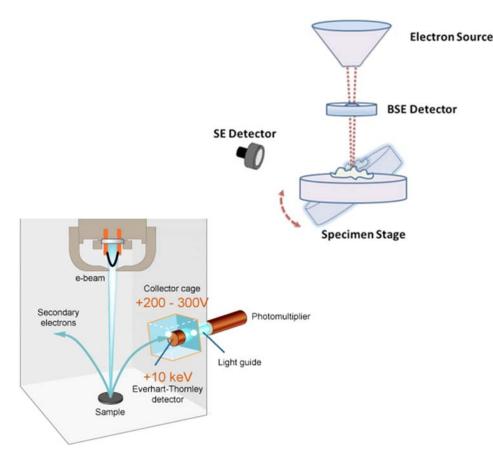
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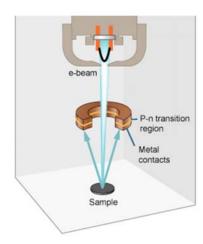
**Plasmons** 

Sample heating (phonons)



### **Electron detectors**

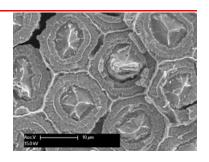


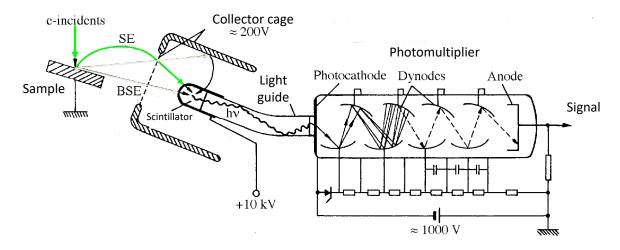


https://myscope.training/legacy/sem/background/what is sem/detectors.php

## **Detection of low energy electrons**

- Photomultiplier
- Everhart-Thornley detector



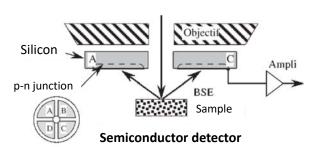


Collects and detects low energy (<100eV) electrons: SEM secondary electrons



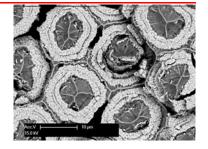
## **Detection of high energy electrons**

Semiconductor detector



BSE semiconductor detector: a silicon diode with a p-n junction close to its surface collects the BSE (3.8eV/ehole pair)

- large collection angle
- slow (poor at TV frequency)
- some diodes are split in 2 or 4 quadrants to bring spatial BSE distribution information



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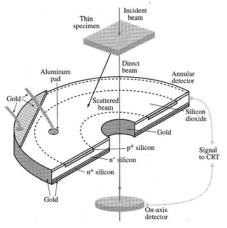


Figure 7.1. Semiconductor detector of the surface-barrier type, shown in a configuration where it would be used to detect high-energy forward-scattered electrons. The direct beam is detected by a small circular detector on the optic axis surrounded by a concentric wide-angle annular detector, which detects any explant alteriors.

Detects higher energy (>5kV) electrons: SEM backscattered electrons